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April 2016

# FGA30S120P 1300 V, 30 A Shorted-anode IGBT

### **Features**

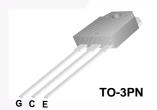
- · High Speed Switching
- Low Saturation Voltage:  $V_{CE(sat)} = 1.75 \text{ V } @ I_{C} = 30 \text{ A}$
- High Input Impedance
- RoHS Compliant

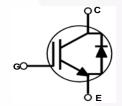
## **Applications**

• Induction Heating, Microwave Oven

### **General Description**

Using advanced field stop trench and shorted-anode technology, Fairchild's shorted-anode Trench IGBTs offer superior conduction and switching performances for soft switching applications. The device can operate in parallel configuration with exceptional avalanche capability. This device is designed for induction heating and microwave oven.





## Absolute Maximum Ratings $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Description		Ratings	Unit	
V <sub>CES</sub>	Collector to Emitter Voltage		1300	V	
$V_{GES}$	Gate to Emitter Voltage		±25	V	
I <sub>C</sub>	Collector Current	$^{\circ}$ T <sub>C</sub> = 25 $^{\circ}$ C	60	Α	
·c	Collector Current	$@ T_C = 100^{\circ}C$	30	Α	
I <sub>CM (1)</sub>	Pulsed Collector Current		150	А	
I <sub>F</sub>	Diode Continuous Forward Current	@ T <sub>C</sub> = 25°C	60	A	
I <sub>F</sub>	Diode Continuous Forward Current	@ T <sub>C</sub> = 100°C	30	A	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	348	W	
	Maximum Power Dissipation	$@ T_C = 100^{\circ}C$	174	W	
TJ	Operating Junction Temperature		-55 to +175	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +175	°C	
T <sub>L</sub>	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case		0.43	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient		40	°C/W

### Notes:

1: Limited by Tjmax

## **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGA30S120P	FGA30S120P	TO-3P	Tube	N/A	N/A	30

## Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics		<u>'</u>	II.		
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V}, I_{C} = 1 \text{ mA}$	1300	-	-	V
ΔBV <sub>CES</sub> / ΔΤ <sub>J</sub>	Temperature Coefficient of Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 1 mA	-	1.3	-	V/°C
I <sub>CES</sub>	Collector Cut-Off Current	V <sub>CE</sub> = 1300, V <sub>GE</sub> = 0V	-	-	1	mA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	±500	nA
On Charac	teristics			l		
V <sub>GE(th)</sub>	G-E Threshold Voltage	$I_C = 30$ mA, $V_{CE} = V_{GE}$	4.5	6.0	7.5	V
	Collector to Emitter Saturation Voltage	$I_C = 30A, V_{GE} = 15V$ $T_C = 25^{\circ}C$	-	1.75	2.3	٧
V <sub>CE(sat)</sub> Collecto		$I_C = 30A, V_{GE} = 15V,$ $T_C = 125^{\circ}C$	-	1.85	-	٧
		I <sub>C</sub> = 30A, V <sub>GE</sub> = 15V, T <sub>C</sub> = 175°C	-	1.9	-	٧
$V_{FM}$	Diode Forward Voltage	$I_F = 30A, T_C = 25^{\circ}C$	-	1.7	2.2	V
Siede Ferward Vollage		$I_F = 30A, T_C = 175^{\circ}C$	-	2.1	-	V
Dynamic C	haracteristics					
C <sub>ies</sub>	Input Capacitance		-	3345	-	pF
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 30V_{,} V_{GE} = 0V_{,}$ f = 1MHz	-	75	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance	1 - 1101112	-	60	-	pF
Switching	Characcteristics				1	
t <sub>d(on)</sub>	Turn-On Delay Time		-	39	-	ns
t <sub>r</sub>	Rise Time		-	360	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{CC} = 600V, I_{C} = 30A,$	-	620	-	ns
t <sub>f</sub>	Fall Time	$R_G = 10\Omega$ , $V_{GE} = 15V$ ,	-	160	-	ns
E <sub>on</sub>	Turn-On Switching Loss	Resistive Load, T <sub>C</sub> = 25°C	- /	1.3	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	1.22	-	mJ
E <sub>ts</sub>	Total Switching Loss		-	2.52	-	mJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	38	-	ns
t <sub>r</sub>	Rise Time		-	375	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{CC} = 600V, I_{C} = 30A,$	-	635	- /	ns
t <sub>f</sub>	Fall Time	$R_G = 10\Omega, V_{GE} = 15V,$	-	270	- (	ns
E <sub>on</sub>	Turn-On Switching Loss	Resistive Load, T <sub>C</sub> = 175°C	-	1.59	- \	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	1.78	_	mJ
E <sub>ts</sub>	Total Switching Loss		-	3.37		mJ
Qg	Total Gate Charge		-	78	-	nC
Q <sub>ge</sub>	Gate to Emitter Charge	$V_{CE} = 600V, I_{C} = 30A,$ $V_{GE} = 15V$	-	4.2	-	nC
Q <sub>gc</sub>	Gate to Collector Charge	- GE	-	33.3	-	nC

## **Typical Performance Characteristics**

**Figure 1. Typical Output Characteristics** 

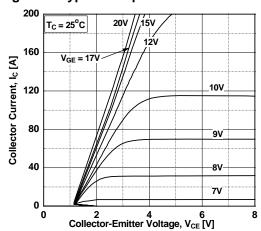


Figure 3. Typical Saturation Voltage Characteritics

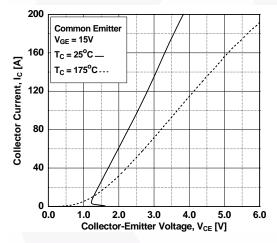
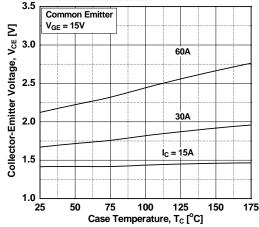


Figure 5. Saturation Voltage vs. Case
Temperature at Variant Current Level



**Figure 2. Typical Output Characteristics** 

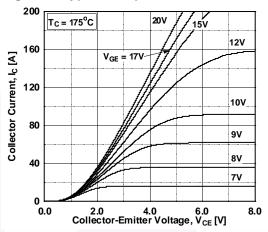


Figure 4. Transfer Characteristics

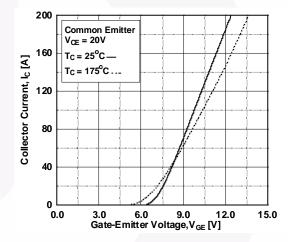
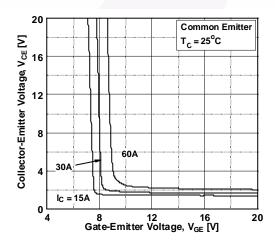


Figure 6. Saturation Voltage vs. Vge



## **Typical Performance Characteristics**

Figure 7. Saturation Voltage vs. VgE

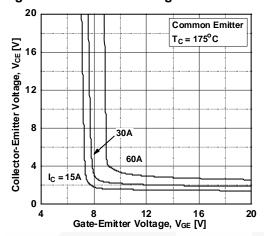


Figure 9. Gate Charge Characteristics

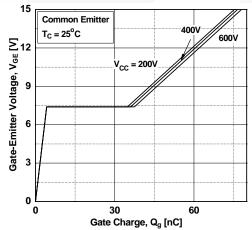
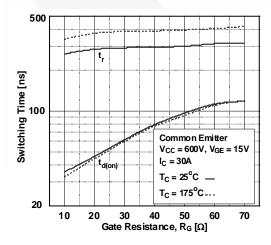


Figure 11. Turn-On Characteristics vs Gate Resistance



**Figure 8. Capacitance Characteristics** 

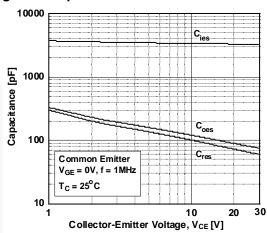


Figure 10. SOA Characteeristics

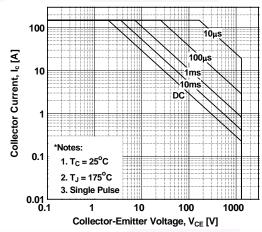
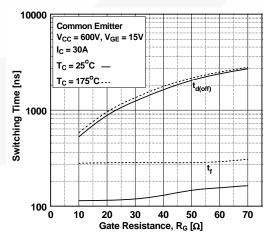


Figure 12. Turn-off Characteristics vs.
Gate Resistance



## **Typical Performance Characteristics**

Figure 13. Turn-on Characteristics VS. Collector Current

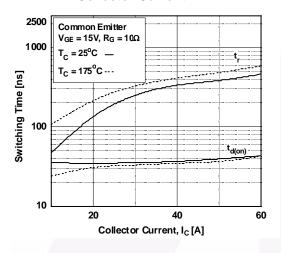


Figure 14.Turn-off Characteristics VS. Collector Current

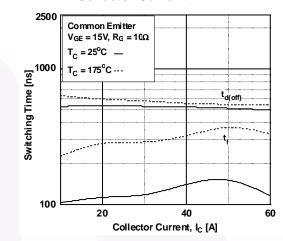


Figure 15. Switching Loss VS. Gate Resistance

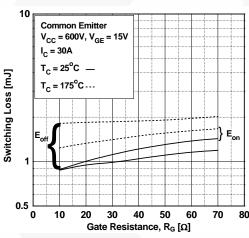


Figure 16. Switching Loss VS. Collector Current

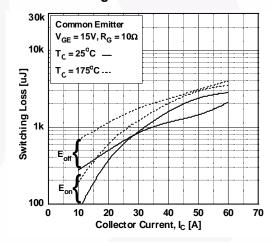


Figure 17. Turn off Switching SOA Characteristics

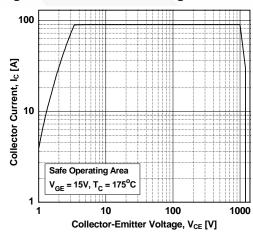


Figure 18. Forward Characteristics

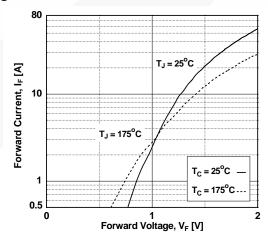
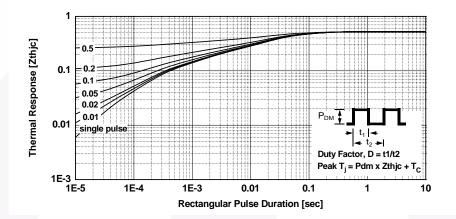
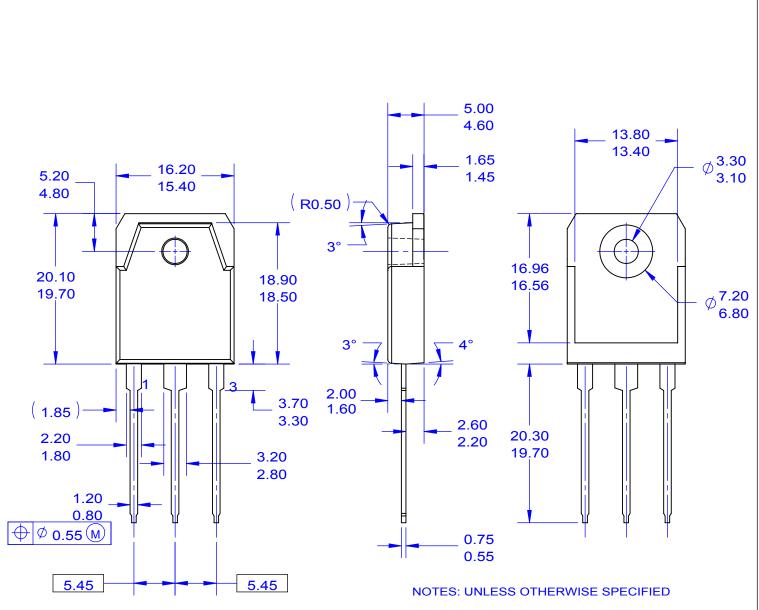
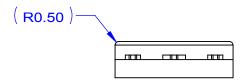


Figure 19. Transient Thermal Impedance of IGBT







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